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10G XGSPON BOSA BA-53 series T10G/R10G

Description

This BOSA is a high performance optical sub-assembly in single fiber by using 1270nm transmitter and 1577nm receiver.

The transmitter section uses a multiple quantum well 1270nm DFB laser supporting burst-mode operation. The receiver section uses an integrated 1577nm APD and preamplifier mounted in a TO-can.

Applications

- 10G XGSPON symmetric SFP+ transceiver, ONU
- 10 Gigabit Ethernet Access Networks

Features

- Single fiber pigtail type bi-directional transmission design for 10G XGPON ONU
- Symmetric 10Gbps Tx burst mode and 10Gbps Rx CW data rate
- Integrated micro-optics WDM filters for dual wavelength Tx/Rx operation at 1270/1577nm
- 1270nm InGaAsP/InP MQW DFB laser diode transmission with InGaAs monitor photodiode
- 1577nm digital APD-TIA continuous mode receiver
- Flex PCB standard pin-out
- Optical reflection free with built-in 1270nm free space isolator
- High optical isolation from external 1490nm source, and low optical cross-talk from internal 1270nm source
- 0°C to +70°C commercial temperature with excellent temperature dependent power tracking error

Standard

- ITU-T 987.2 10G XGPON-2 communication protocol
- Compliant with Telcordia GR-468 reliability test criterion
- Compliant with RoHS6 standard

1. Absolute Maximum Ratings

Item	Unit	Min	Max	Note
Forward Current for LD	mA	—	120	
Reverse Voltage for LD	V	—	2	
Forward Current for MPD	mA	—	2	
Reverse Voltage for MPD	V	—	20	
APD Reverse Voltage	V	—	Vbr	
TIA Supply Voltage	V	-0.4	4	
Operating Temp	°C	0	70	
Storage Temperature	°C	-40	85	
Storage Relative Humidity	%	—	85	
Soldering Temperature	°C	—	260	(*1)
ESD threshold	V	500		

(*1): For soldering by iron and 10 seconds on leads

2. Transmitter Electro-Optical Characteristics ($T_c=25^\circ\text{C}$, CW)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Transmitter Bit Rate		0~70°C	—	9.953	—	Gbps
Threshold Current	I _{th}	25°C	—	8	15	mA
		0~70°C	—	—	50	mA
Optical Output Power (*2)	P _f	I _f =I _{th} +20mA	2.5	—	—	mW
		I _f =I _{th} +20mA, 0~70°C	1.5	—	—	mW
Forward Voltage	V _f	I _f =I _{th} +20mA	—	1.1	1.8	V
Peak Wavelength	λ _c	I _f =I _{th} +20mA	1260	1270	1280	nm
Side Mode Suppression Ratio	SMSR	I _f =I _{th} +20mA, 0~70°C	30	—	—	dB
Monitor Current	I _m	I _f =I _{th} +20mA	100	—	1200	μA
Tracking Error (*3)	TE	T _c =0~70°C	-1.5	—	1.5	dB

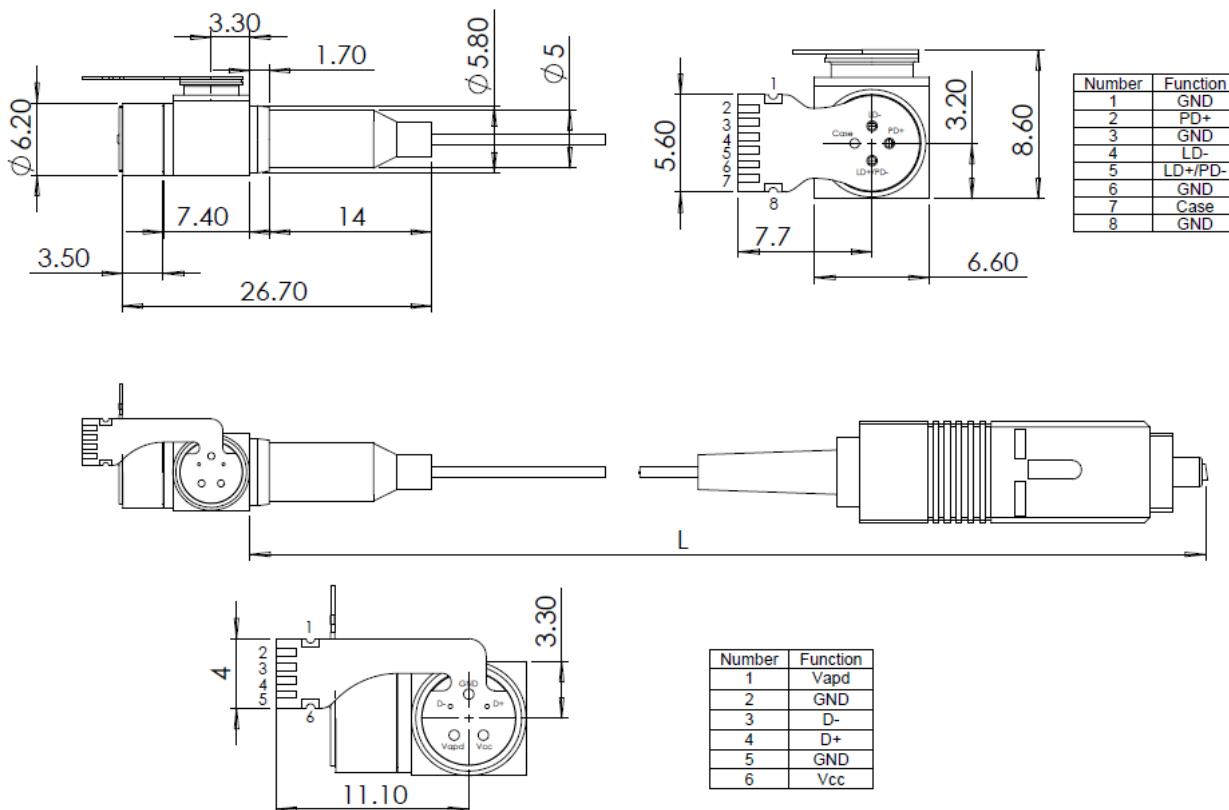
(*2): Launched into 9/125μm SMF, measured with a master plug and an extra receptacle

(*3): $\Delta P_f = 10 \times \log(P_f(T_c)/P_f(25^\circ\text{C}))$, I_m hold(@P_f=2.5mW, 25°C)

3. Receiver Electro-Optical Characteristics (TC=25°C, Vcc=3.3V)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Supply Voltage	Vcc	No loads	3.0	3.3	3.6	V
Supply Current	Icc	No loads	-	-	50	mA
Operating Wavelength	λ		1575	1577	1580	nm
Sensitivity	Sen	9.953Gbps, NRZ, PRBS23, ER=8.2dB, BER=10E-3	-	-	-29.5	dBm
Overload	OL		-7.0	-	-	dBm
Breakdown Voltage	Vbr	Id=10μA	22	-	45	V
Optical Return Loss	RL	λ=1270nm	10	-	-	dB
		λ=1577nm	20	-	-	dB
Optical Crosstalk	X-talk		-	-45	-40	dB
Optical Isolation from External Source	ISO	λ=1260~1560nm	35	-	-	dB
		λ=1600~1675nm	35	-	-	dB

4. Dimension Outline



5. Other Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Mode Field Diameter		8	9	10	μm	
Gladding Diameter		123	125	127	μm	
Fiber Macro bend Loss				0.05	dB	Radius 16mm
Optical Connector Insertion Loss		–	–	0.4	dB	SC/APC connector
Fiber Bending Radius		25	–	–	mm	
Fiber Diameter		0.8	0.9	1.0	mm	
Fiber Length		280	–	340	mm	L
Pull Force on LD Assembly		30	–	–	Kgw	
Pull Force on APD Assembly		15	–	–	Kgw	
Shear Strength on XY Welding		30	–	–	Kgw	
Tension Force on Fiber Pigtail		5	–	–	N	

(*4): Connector fiber end face accord with IPC-8497-1